Low-power dual buffer/line driver; 3-state Rev. 15 — 26 July 2023

Product data sheet

1. General description

The 74AUP2G125 is a dual buffer/line driver with 3-state outputs controlled by the output enable inputs ($n\overline{OE}$). Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall times. This device ensures very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

This device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- CMOS low power dissipation
- Low static power consumption; I_{CC} = 0.9 μA (maximum)
- Latch-up performance exceeds 100 mA per JESD78B Class II
- Overvoltage tolerant inputs to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- Input-disable feature allows floating input conditions
- I_{OFF} circuitry provides partial Power-down mode operation
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- Complies with JEDEC standards:
 - JESD8-12 (0.8 V to 1.3 V)
 - JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.2 V to 1.95 V)
 - JESD8-5 (1.8 V to 2.7 V)
 - JESD8-B (2.7 V to 3.6 V)
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 3A exceeds 5000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

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3. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74AUP2G125DC	-40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package; 8 leads; body width 2.3 mm	<u>SOT765-1</u>
74AUP2G125GT	-40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body 1 × 1.95 × 0.5 mm	<u>SOT833-1</u>
74AUP2G125GF	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 × 1 × 0.5 mm	<u>SOT1089</u>
74AUP2G125GN	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.2 × 1.0 × 0.35 mm	<u>SOT1116</u>
74AUP2G125GS	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 × 1.0 × 0.35 mm	<u>SOT1203</u>
74AUP2G125GX	-40 °C to +125 °C	X2SON8	plastic thermal enhanced extremely thin small outline package; no leads; 8 terminals; body 1.35 × 0.8 × 0.32 mm	<u>SOT1233-2</u>

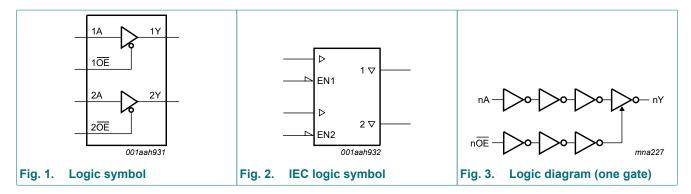
4. Marking

Table 2. Marking codes

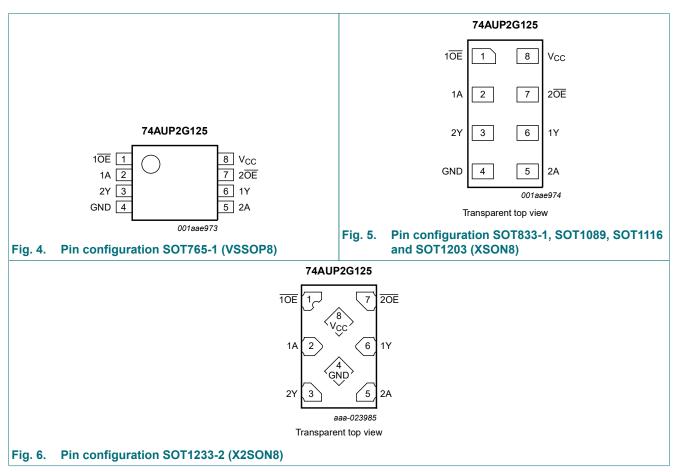
Type number	Marking code[1]
74AUP2G125DC	p25
74AUP2G125GT	p25
74AUP2G125GF	aM
74AUP2G125GN	aM
74AUP2G125GS	aM
74AUP2G125GX	aM

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



6. Pinning information



6.1. Pinning

6.2. Pin description

Symbol	Pin	Description
10E, 20E	1, 7	output enable input (active LOW)
1A, 2A	2, 5	data input
GND	4	ground (0 V)
1Y, 2Y	6, 3	data output
V _{CC}	8	supply voltage

7. Functional description

Table 4. Function table

H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

Input O nOE nA n		Output
nŌE	nA	nY
L	L	L
L	Н	Н
Н	X	Z

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Мах	Unit
V _{CC}	supply voltage			-0.5	+4.6	V
VI	input voltage		[1]	-0.5	+4.6	V
Vo	output voltage	Active mode and Power-down mode	[1]	-0.5	+4.6	V
I _{IK}	input clamping current	V ₁ < 0 V		-50	-	mA
I _{OK}	output clamping current	V _O < 0 V		-50	-	mA
I _O	output current	$V_{O} = 0 V \text{ to } V_{CC}$		-	±20	mA
I _{CC}	supply current			-	+50	mA
I _{GND}	ground current			-50	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C				
		SOT765-1 (VSSOP8) SOT833-1 (XSON8) SOT1089 (XSON8) SOT1116 (XSON8) SOT1203 (XSON8)	[2] [3] [4] [5] [6]		250 250 250 250 250 250	mW mW mW mW mW
		SOT1233-2 (X2SON8)	[7]	-	300	mW

The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed. [1]

[2] For SOT765-1 (VSSOP8) package: Ptot derates linearly with 4.9 mW/K above 99 °C.

For SOT833-1 (XSON8) package: Ptot derates linearly with 3.1 mW/K above 68 °C. [3]

For SOT1089 (XSON8) package: P_{tot} derates linearly with 4.0 mW/K above 88 °C. For SOT1116 (XSON8) package: P_{tot} derates linearly with 4.2 mW/K above 90 °C. For SOT1203 (XSON8) package: P_{tot} derates linearly with 3.6 mW/K above 81 °C. [4]

[5]

[6]

For SOT1233-2 (X2SON8) package: Ptot derates linearly with 7.7 mW/K above 118 °C. [7]

9. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V _{CC}	V
		Power-down mode; V _{CC} = 0 V	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 0.8 V to 3.6 V	-	200	ns/V

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
T _{amb} = 2	5 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 0.8 V	0.70 × V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	0.65 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.30 × V _{CC}	V
		V _{CC} = 0.9 V to 1.95 V	-	-	0.35 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.75 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.11	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.32	-	-	V
		I_0 = -2.3 mA; V_{CC} = 2.3 V	2.05	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.9	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.72	-	-	V
		I_0 = -4.0 mA; V_{CC} = 3.0 V	2.6	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_0 = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.31	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.31	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.44	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.31	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.44	V

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
l _l	input leakage current	V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.1	μA
I _{OZ}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = 0 \text{ V to } 3.6 \text{ V}; V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	-	±0.1	μA
I _{OFF}	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.2	μA
ΔI_{OFF}	additional power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.2	μA
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.5	μA
ΔI _{CC}	additional supply current	data input; V _I = V _{CC} - 0.6 V; I _O = 0 A; [1] V _{CC} = 3.3 V	-	-	40	μA
		$\overline{\text{NOE}}$ input; V ₁ = V _{CC} - 0.6 V; I _O = 0 A; [1] V _{CC} = 3.3 V	-	-	110	μA
		all inputs; V _I = GND to 3.6 V; [2] $n\overline{OE}$ = GND; V _{CC} = 0.8 V to 3.6 V	-	-	1	μA
CI	input capacitance	V_{CC} = 0 V to 3.6 V; V _I = GND or V _{CC}	-	0.8	-	pF
Co	output capacitance	output enabled; V_0 = GND; V_{CC} = 0 V	-	1.4	-	pF
		output disabled; $V_O = GND \text{ or } V_{CC} = 0 \text{ V};$ $V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	1.3	-	pF

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Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
T _{amb} = -4	0 °C to +85 °C					
VIH	HIGH-level input voltage	V _{CC} = 0.8 V	0.70 × V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	0.65 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.30 × V _{CC}	V
		V _{CC} = 0.9 V to 1.95 V	-	-	0.35 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}				
		I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.7 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.03	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.30	-	-	V
		I_0 = -2.3 mA; V_{CC} = 2.3 V	1.97	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.85	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.67	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.55	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_0 = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.37	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.35	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.33	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.45	V
l _l	input leakage current	V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.5	μA
I _{OZ}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = 0 \text{ V to } 3.6 \text{ V}; V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	-	±0.5	μA
I _{OFF}	power-off leakage current	$V_{I} \text{ or } V_{O} = 0 \text{ V to } 3.6 \text{ V}; V_{CC} = 0 \text{ V}$	-	-	±0.5	μA
ΔI _{OFF}	additional power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.6	μA
I _{CC}	supply current	V_1 = GND or V_{CC} ; I_0 = 0 A; V_{CC} = 0.8 V to 3.6 V	-	-	0.9	μA
ΔI _{CC}	additional supply current	data input; V ₁ = V _{CC} - 0.6 V; I _O = 0 A; [1] V _{CC} = 3.3 V	-	-	50	μA
		$\overline{\text{NOE}}$ input; V _I = V _{CC} - 0.6 V; I _O = 0 A; [1] V _{CC} = 3.3 V	-	-	120	μA
		all inputs; V_1 = GND to 3.6 V; [2] n \overline{OE} = GND; V_{CC} = 0.8 V to 3.6 V	-	-	1	μA

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
T _{amb} = -4	0 °C to +125 °C				I	1
V _{IH}	HIGH-level input voltage	V _{CC} = 0.8 V	0.75 × V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	$0.70 \times V_{CC}$	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V				
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.25 × V _{CC}	V
		V _{CC} = 0.9 V to 1.95 V	-	-	0.30 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{он}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.11	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.6 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	0.93	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.17	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.77	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.67	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.40	-	-	V
		$I_0 = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.30	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
01		$I_{O} = 20 \ \mu A; V_{CC} = 0.8 \ V \ to \ 3.6 \ V$	-	-	0.11	V
		$I_0 = 1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	-	-	0.33 × V _{CC}	V
		$I_0 = 1.7 \text{ mA; } V_{CC} = 1.4 \text{ V}$	-	-	0.41	V
		$I_0 = 1.9 \text{ mA; } V_{CC} = 1.65 \text{ V}$	-	-	0.39	V
		$I_0 = 2.3 \text{ mA; } V_{CC} = 2.3 \text{ V}$	-	-	0.36	V
		$I_0 = 3.1 \text{ mA; } V_{CC} = 2.3 \text{ V}$	-	-	0.50	V
		$I_0 = 2.7 \text{ mA; } V_{CC} = 3.0 \text{ V}$	-	-	0.36	V
		$I_0 = 4.0 \text{ mA; } V_{CC} = 3.0 \text{ V}$	-	-	0.50	V
l	input leakage current	$V_{\rm I} = {\rm GND \ to \ 3.6 \ V}; V_{\rm CC} = 0 \ V \ {\rm to \ 3.6 \ V}$	_	_	±0.75	μA
I _{OZ}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	-	±0.75	μA
I _{OFF}	power-off leakage current	$V_{\rm I}$ or $V_{\rm O}$ = 0 V to 3.6 V; $V_{\rm CC}$ = 0 V	-	-	±0.75	μA
ΔI _{OFF}	additional power-off leakage current	$V_{I} \text{ or } V_{O} = 0 \text{ V to } 3.6 \text{ V;}$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.75	μA
сс	supply current	V_1 = GND or V_{CC} ; I_0 = 0 A; V_{CC} = 0.8 V to 3.6 V	-	-	1.4	μA
ΔI _{CC}	additional supply current	data input; V ₁ = V _{CC} - 0.6 V; I _O = 0 A; [1] V _{CC} = 3.3 V	-	-	75	μA
		$n\overline{OE}$ input; V _I = V _{CC} - 0.6 V; I _O = 0 A; [1] V _{CC} = 3.3 V	-	-	180	μA
		all inputs; V_1 = GND to 3.6 V; [2] n \overline{OE} = GND; V_{CC} = 0.8 V to 3.6 V	-	-	1	μA

[1] [2]

One input at V_{CC} - 0.6 V, other input at V_{CC} or GND. To show I_{CC} remains very low when the input-disable feature is enabled.

11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 9.

Symbol	Parameter	Conditions		25 °C		T _{an} -40 °C te	_{nb} = o +85 °C	T _{amb} = -40 °C to +125 °C		Unit
			Min	Typ[1]	Мах	Min	Max	Min	Max	
C _L = 5 p	F									
t _{pd}	propagation	nA to nY; see <u>Fig. 7</u> . [2]								
	delay	V _{CC} = 0.8 V	-	20.6	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.8	5.5	10.5	2.5	11.7	2.5	12.9	ns
		V _{CC} = 1.4 V to 1.6 V	2.2	3.9	6.1	2.0	7.3	2.0	8.1	ns
		V _{CC} = 1.65 V to 1.95 V	1.9	3.2	4.8	1.7	6.1	1.7	6.7	ns
		V _{CC} = 2.3 V to 2.7 V	1.6	2.6	3.6	1.4	4.3	1.4	4.9	ns
		V _{CC} = 3.0 V to 3.6 V	1.4	2.4	3.1	1.2	3.9	1.2	4.4	ns
t _{en}	enable time	nOE to nY; see Fig. 8. [3]								
		V _{CC} = 0.8 V	-	69.9	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.1	6.1	11.8	2.9	13.9	2.9	15.4	ns
		V _{CC} = 1.4 V to 1.6 V	2.5	4.2	6.6	2.3	7.7	2.3	8.3	ns
		V _{CC} = 1.65 V to 1.95 V	2.1	3.4	5.1	2.0	6.2	2.0	6.8	ns
		V _{CC} = 2.3 V to 2.7 V	1.8	2.6	3.7	1.7	4.5	1.7	5.0	ns
		V _{CC} = 3.0 V to 3.6 V	1.7	2.4	3.1	1.7	3.5	1.7	3.9	ns
t _{dis}	disable time	nOE to nY; see Fig. 8. [4]								
		V _{CC} = 0.8 V	-	14.3	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.7	4.3	6.5	2.7	7.3	2.7	8.2	ns
		V _{CC} = 1.4 V to 1.6 V	2.1	3.2	4.4	2.1	5.1	2.1	5.7	ns
		V _{CC} = 1.65 V to 1.95 V	2.0	3.0	4.3	2.0	5.0	2.0	5.7	ns
		V _{CC} = 2.3 V to 2.7 V	1.4	2.2	2.9	1.4	3.3	1.4	4.1	ns
		V _{CC} = 3.0 V to 3.6 V	1.7	2.5	3.2	1.7	3.4	1.7	3.9	ns

Low-power dual buffer/line driver; 3-state

Symbol	Parameter	Conditions		25 °C		T _{an} -40 °C te	_{nb} = o +85 °C	T _{amb} = -40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
C _L = 10	pF									
t _{pd}	propagation	nA to nY; see <u>Fig. 7</u> . [2]								
	delay	V _{CC} = 0.8 V	-	24.0	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.2	6.4	12.3	3.0	13.8	3.0	15.2	ns
		V _{CC} = 1.4 V to 1.6 V	2.1	4.5	7.3	1.9	8.5	1.9	9.4	ns
		V _{CC} = 1.65 V to 1.95 V	1.9	3.8	5.5	1.7	6.8	1.7	7.6	ns
		V _{CC} = 2.3 V to 2.7 V	2.1	3.2	4.2	1.6	5.3	1.6	5.9	ns
		V _{CC} = 3.0 V to 3.6 V	1.8	3.0	3.8	1.6	4.6	1.6	5.2	ns
t _{en}	enable time	nOE to nY; see Fig. 8. [3]								
		V _{CC} = 0.8 V	-	73.7	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.6	6.9	13.5	3.4	15.8	3.4	17.5	ns
		V _{CC} = 1.4 V to 1.6 V	2.3	4.8	7.7	2.2	8.6	2.2	9.4	ns
		V _{CC} = 1.65 V to 1.95 V	2.0	3.9	5.8	1.9	6.8	1.9	7.4	ns
		V _{CC} = 2.3 V to 2.7 V	1.8	3.2	4.3	1.7	5.3	1.7	5.9	ns
		V _{CC} = 3.0 V to 3.6 V	1.7	3.0	3.9	1.7	4.3	1.7	4.8	ns
t _{dis}	disable time	nOE to nY; see Fig. 8. [4]								
		V _{CC} = 0.8 V	-	32.7	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.4	5.4	7.9	3.4	8.8	3.4	9.9	ns
		V _{CC} = 1.4 V to 1.6 V	2.2	4.1	5.5	2.2	6.2	2.2	7.1	ns
		V _{CC} = 1.65 V to 1.95 V	2.2	4.2	5.6	1.9	6.3	1.9	7.1	ns
		V _{CC} = 2.3 V to 2.7 V	1.7	3.0	3.8	1.7	4.5	1.7	5.1	ns
		V _{CC} = 3.0 V to 3.6 V	2.1	3.8	4.8	1.7	5.0	1.7	5.6	ns

Low-power dual buffer/line driver; 3-state

Symbol	Parameter	Conditions		25 °C		T _{an} -40 °C te	_{าb} = о +85 °С	T _{ar} -40 °C to	_{nb} = o +125 °C	Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
C _L = 15	pF					1				
t _{pd}	propagation	nA to nY; see <u>Fig. 7</u> . [2]								
	delay	V _{CC} = 0.8 V	-	27.4	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.6	7.2	14.1	3.3	15.8	3.3	17.5	ns
		V _{CC} = 1.4 V to 1.6 V	3.0	5.1	8.1	2.5	9.8	2.5	10.9	ns
		V _{CC} = 1.65 V to 1.95 V	2.2	4.3	6.3	2.0	7.9	2.0	8.8	ns
		V _{CC} = 2.3 V to 2.7 V	2.0	3.7	4.9	1.8	6.0	1.8	6.7	ns
		V _{CC} = 3.0 V to 3.6 V	2.0	3.5	4.4	1.8	5.4	1.8	6.1	ns
t _{en}	enable time	nOE to nY; see Fig. 8. [3]								
		V _{CC} = 0.8 V	-	77.5	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.0	7.7	15.2	3.7	17.6	3.7	19.6	ns
		V _{CC} = 1.4 V to 1.6 V	3.0	5.3	8.4	2.5	9.8	2.5	10.7	ns
		V _{CC} = 1.65 V to 1.95 V	2.3	4.4	6.5	2.1	7.7	2.1	8.5	ns
		V _{CC} = 2.3 V to 2.7 V	2.1	3.6	5.0	2.0	6.1	2.0	6.8	ns
		V _{CC} = 3.0 V to 3.6 V	2.0	3.5	4.4	1.9	4.9	1.9	5.5	ns
t _{dis}	disable time	nOE to nY; see Fig. 8. [4]								
		V _{CC} = 0.8 V	-	60.8	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.3	6.5	9.2	3.7	10.3	3.7	11.6	ns
		V _{CC} = 1.4 V to 1.6 V	3.0	5.0	6.5	2.5	7.4	2.5	8.4	ns
		V _{CC} = 1.65 V to 1.95 V	3.0	5.3	7.0	2.1	7.4	2.1	8.9	ns
		V _{CC} = 2.3 V to 2.7 V	2.1	3.8	4.9	2.0	5.1	2.0	6.4	ns
		V _{CC} = 3.0 V to 3.6 V	2.9	5.0	6.2	1.9	6.6	1.9	7.4	ns

Low-power dual buffer/line driver; 3-state

Symbol	Parameter	Conditions		25 °C		T _{an} -40 °C t	_{nb} = o +85 °C	T _{ar} -40 °C to	_{nb} = o +125 °C	Unit
			Min	Typ[1]	Max	Min	Мах	Min	Мах	
C _L = 30	pF			-					-	
t _{pd}	propagation	nA to nY; see <u>Fig. 7</u> . [2]								
	delay	V _{CC} = 0.8 V	-	37.4	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.8	9.5	19.0	4.4	21.6	4.4	24.0	ns
		V _{CC} = 1.4 V to 1.6 V	4.0	6.7	10.8	3.0	13.0	3.0	14.5	ns
		V _{CC} = 1.65 V to 1.95 V	2.9	5.6	8.4	2.6	10.3	2.6	11.5	ns
		V _{CC} = 2.3 V to 2.7 V	2.7	4.8	6.3	2.5	7.8	2.5	8.7	ns
		V _{CC} = 3.0 V to 3.6 V	2.7	4.6	5.8	2.5	7.5	2.5	8.3	ns
t _{en}	enable time	nOE to nY; see Fig. 8. [3]								
		V _{CC} = 0.8 V	-	88.9	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	5.2	9.9	19.8	4.8	22.8	4.8	25.3	ns
		V _{CC} = 1.4 V to 1.6 V	4.0	6.8	10.8	3.1	12.6	3.1	14.1	ns
		V _{CC} = 1.65 V to 1.95 V	3.0	5.6	8.5	2.8	10.2	2.8	11.3	ns
		V _{CC} = 2.3 V to 2.7 V	2.7	4.8	6.5	2.6	7.8	2.6	8.8	ns
		V _{CC} = 3.0 V to 3.6 V	2.7	4.6	6.0	2.6	6.9	2.6	7.7	ns
t _{dis}	disable time	nOE to nY; see Fig. 8. [4]								
		V _{CC} = 0.8 V	-	49.9	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	6.0	9.9	13.3	4.8	14.8	4.8	16.5	ns
		V _{CC} = 1.4 V to 1.6 V	4.4	7.7	9.6	3.1	10.8	3.1	12.1	ns
		V _{CC} = 1.65 V to 1.95 V	5.1	8.7	11.1	2.8	12.4	2.8	13.8	ns
		V _{CC} = 2.3 V to 2.7 V	3.6	6.2	7.6	2.6	8.6	2.6	9.6	ns
		V _{CC} = 3.0 V to 3.6 V	5.2	8.7	10.5	2.6	10.8	2.6	13.1	ns
C _L = 5 p	F, 10 pF, 15 p	F and 30 pF				1				
C _{PD}	power dissipation	output enabled; $f_i = 1 \text{ MHz}$; [5] $V_1 = \text{GND}$ to V_{CC}								
	capacitance	V _{CC} = 0.8 V	-	2.7	-	-	-	-	-	pF
		V _{CC} = 1.1 V to 1.3 V	-	2.8	-	-	-	-	-	pF
		V _{CC} = 1.4 V to 1.6 V	-	2.9	-	-	-	-	-	pF
		V _{CC} = 1.65 V to 1.95 V	-	3.0	-	-	-	-	-	pF
		V _{CC} = 2.3 V to 2.7 V	-	3.6	-	-	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V	-	4.2	-	-	-	-	-	pF

[1] All typical values are measured at nominal V_{CC} .

 t_{pd} is the same as t_{PLH} and t_{PHL} . [2]

[3] \dot{t}_{en} is the same as t_{PZH} and t_{PZL} .

[4] t_{dis} is the same as t_{PHZ} and t_{PLZ} . [5] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

 f_o = output frequency in MHz;

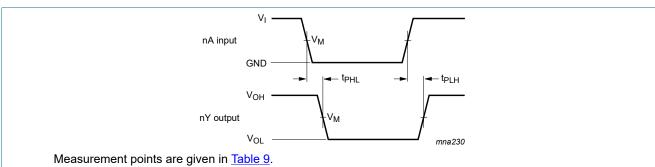
C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o) = \text{sum of outputs.}$



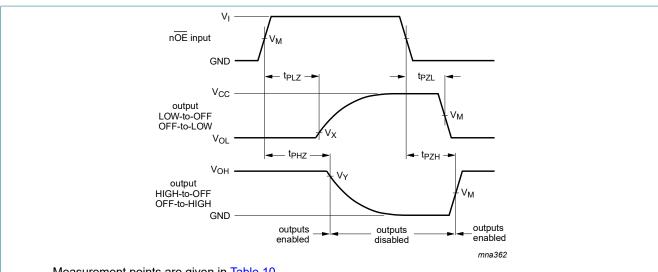


Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig. 7. The data input (nA) to output (nY) propagation delays

Table 9. Measurement points

Supply voltage	Input			Output
V _{cc}	V _M	VI	t _r = t _f	V _M
0.8 V to 3.6 V	$0.5 \times V_{CC}$	V _{CC}	≤ 3.0 ns	0.5 × V _{CC}



Measurement points are given in Table 10.

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Enable and disable times Fig. 8.

Table 10. Measurement points Supply voltage Output Input Vcc VM VM Vx Vy 0.8 V to 1.6 V $0.5 \times V_{CC}$ V_{OL} + 0.1 V $0.5 \times V_{CC}$ V_{OH} - 0.1 V 1.65 V to 2.7 V V_{OL} + 0.15 V V_{OH} - 0.15 V 0.5 × V_{CC} $0.5 \times V_{CC}$ 3.0 V to 3.6 V $0.5 \times V_{CC}$ $0.5 \times V_{CC}$ V_{OL} + 0.3 V V_{OH} - 0.3 V

Low-power dual buffer/line driver; 3-state

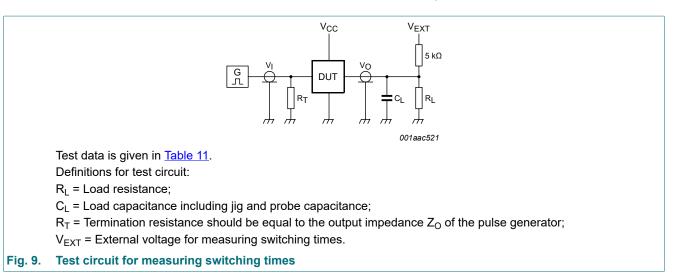


Table 11. Test data

Supply voltage	Load		V _{EXT}		
V _{cc}	CL	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	$2 \times V_{CC}$

[1] For measuring enable and disable times $R_L = 5 k\Omega$.

For measuring propagation delays, setup and hold times and pulse width R_L = 1 M Ω .

12. Package outline

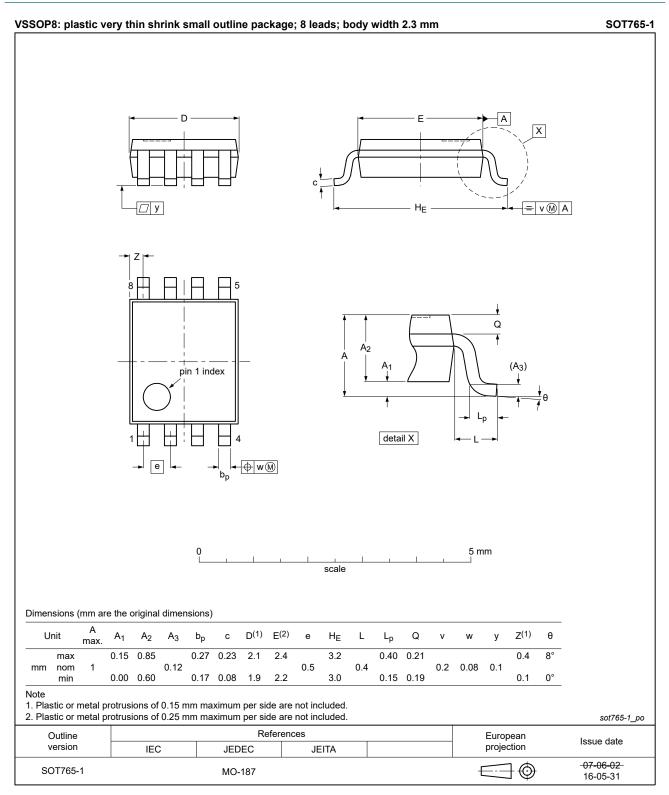


Fig. 10. Package outline SOT765-1 (VSSOP8)

Low-power dual buffer/line driver; 3-state

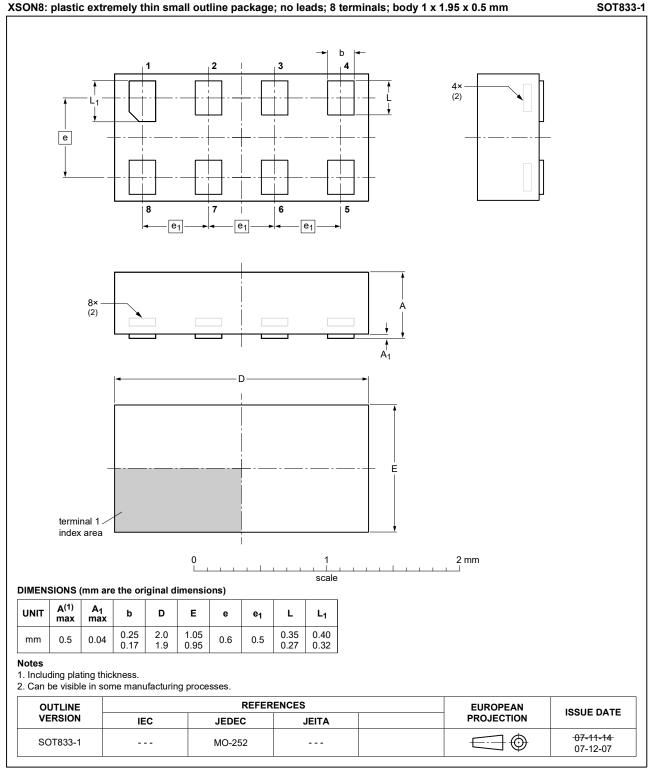
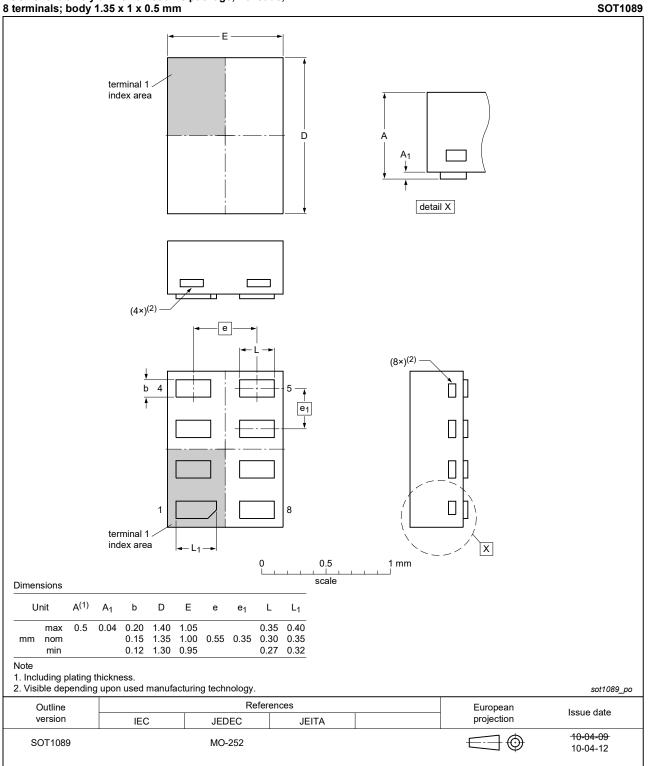


Fig. 11. Package outline SOT833-1 (XSON8)

Low-power dual buffer/line driver; 3-state

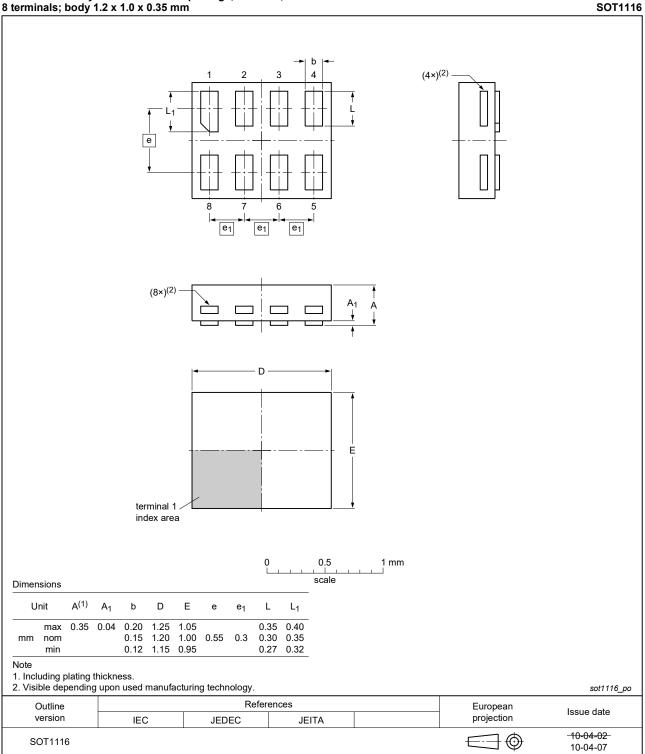


XSON8: extremely thin small outline package; no leads; 8 terminals; body 1.35 x 1 x 0.5 mm

Fig. 12. Package outline SOT1089 (XSON8)

Low-power dual buffer/line driver; 3-state

XSON8: extremely thin small outline package; no leads; 8 terminals; body 1.2 x 1.0 x 0.35 mm





Low-power dual buffer/line driver; 3-state

XSON8: extremely thin small outline package; no leads; 8 terminals; body 1.35 x 1.0 x 0.35 mm SOT1203 b (4×)⁽²⁾ 4 2 3 е 8 6 e₁ e₁ e₁ $(8 \times)^{(2)}$ А С С ٦ D E terminal 1 index area 0.5 1 mm 0 1 1 1 scale Dimensions Unit A⁽¹⁾ A₁ b D Е L е e₁ L_1 0.35 0.04 0.20 1.40 1.05 0.35 0.40 max 0.15 1.00 0.55 0.35 0.30 0.35mm nom 1.35 min 0.12 1.30 0.95 0.27 0.32 Note 1. Including plating thickness. 2. Visible depending upon used manufacturing technology. sot1203_po References Outline European Issue date version projection IEC JEDEC JEITA 10-04-02 SOT1203 \blacksquare 10-04-06

Fig. 14. Package outline SOT1203 (XSON8)

Low-power dual buffer/line driver; 3-state

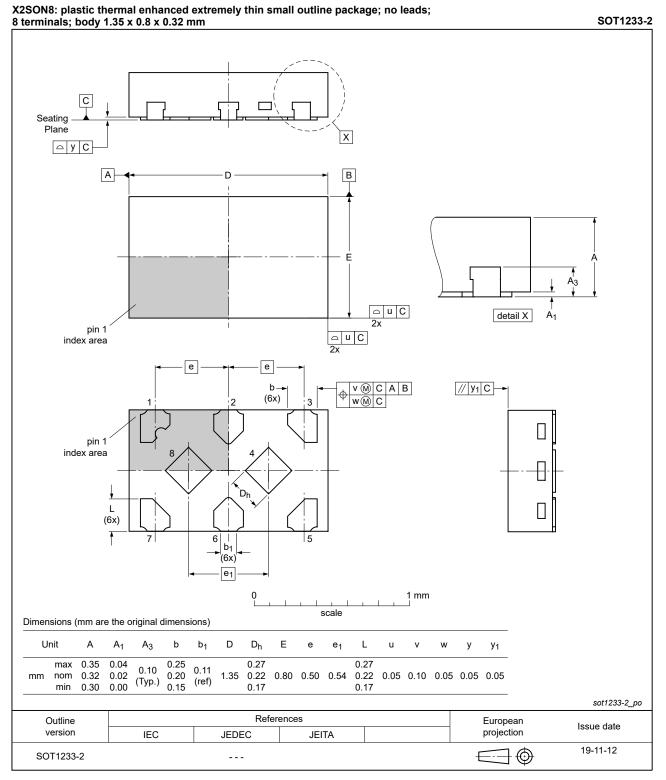


Fig. 15. Package outline SOT1233-2 (X2SON8)

13. Abbreviations

Table 12. Abbreviat	ions
Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model

14. Revision history

Table 13. Revision history Document ID Release date Data sheet status **Change notice** Supersedes 74AUP2G125 v.15 20230726 Product data sheet 74AUP2G125 v.14 Modifications: Section 2: ESD specification updated according to the latest JEDEC standard. 74AUP2G125 v.14 20220621 Product data sheet 74AUP2G125 v.13 Modifications: Package SOT1233 (X2SON8) changed to SOT1233-2 (X2SON8). • 74AUP2G125 v.13 20220310 Product data sheet 74AUP2G125 v.12 Modifications: Type number 74AUP2G125GM (SOT902-2/XQFN8) removed. • Section 1 and Section 2 updated. Table 5: Derating values for Ptot total power dissipation have been updated. 74AUP2G125 v.12 20170703 Product data sheet 74AUP2G125 v.11 Modifications: The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Fig. 6 and Fig. 15 (drawings SOT1233/X2SON8) updated • Type number 74AUP2G125GD removed. 74AUP2G125 v.11 20161028 Product data sheet 74AUP2G125 v.10 Modifications: Added type number 74AUP2G125GX (SOT1233/X2SON8) 74AUP2G125 v.10 20130208 Product data sheet 74AUP2G125 v.9 Modifications: For type number 74AUP2G125GD XSON8U has changed to XSON8. • 74AUP2G125 v.9 20120607 Product data sheet 74AUP2G125 v.8 74AUP2G125 v.8 20111202 Product data sheet 74AUP2G125 v.7 74AUP2G125 v.7 20100921 Product data sheet 74AUP2G125 v.6 74AUP2G125 v.6 20091127 Product data sheet 74AUP2G125 v.5 74AUP2G125 v.5 20090202 Product data sheet 74AUP2G125 v.4 74AUP2G125 v.4 20090122 Product data sheet 74AUP2G125 v.3 74AUP2G125 v.3 20080409 Product data sheet 74AUP2G125 v.2 74AUP2G125 v.2 74AUP2G125 v.1 20070419 Product data sheet 74AUP2G125 v.1 20061017 Product data sheet

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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Product data sheet

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